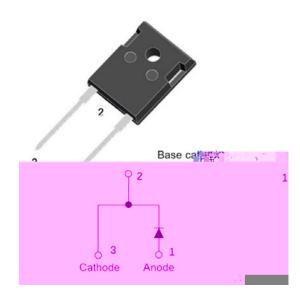


# YJD106520NQG2



# Silicon Carbide Schottky Diode

$V_{RRM}$	650V		
I <sub>F 135°C</sub>	26A		
$Q_{C}$	62nC		



### **Features**

Positive temperature coefficient
Temperature-independent switching
Maximum working temperature at 175 °C
Unipolar devices and zero reverse recovery current
Zero forward recovery current
Essentially no switching losses
Reduction of heat sink requirements
High-frequency operation
Reduction of EMI

## **Typical Applications**

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

### **Mechanical Data**

Package: TO-247AC

Molding compound meets UL 94 V-0 flammability

rating, RoHS-compliant, halogen-free

Terminals: Tin plated leads

Polarity: As marked

## **Maximum Ratings** (T<sub>C</sub>=25 Unless otherwise specified)

PARAMTETER	SYMBOL	UNIT	VALUE
Device marking code			D106520NQG2
Reverse voltage (repetitive peak) @ T <sub>i</sub> =25°C	$V_{RRM}$	V	650
Reverse voltage (Surge Peak) @ T <sub>j</sub> =25°C	$V_{RSM}$	V	650
Reverse voltage (DC) @ T <sub>j</sub> =25°C	V <sub>DC</sub>	V	650
Continuous forward current @ T <sub>c</sub> =25°C			56
Continuous forward current @ T <sub>c</sub> =135°C	I <sub>F</sub>	А	26
Continuous forward current @ T <sub>c</sub> =148°C			20
Non-repetitive peak forward surge current @ T <sub>c</sub> =25°C, tp=10ms, Half Sine Wave	I <sub>FSM</sub>	А	160
Power Dissipation@ T <sub>c</sub> =25°C		W	187
Power Dissipation@ T <sub>c</sub> =110°C	- P <sub>TOT</sub>		81
i²t Value@ Tc=25°C ,tp=10ms	i <sup>2</sup> dt	A <sup>2</sup> S	128
Operating junction and Storage temperature range	$T_{j}$ , $T_{stg}$	°C	-55 to +175



# YJD106520NQG2



**Electrical Characteristics** (Per Leg)

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PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.	
			I <sub>F</sub> =20A, T <sub>j</sub> =25°C	1.35		
Forward voltage drop	$V_{F}$	V				



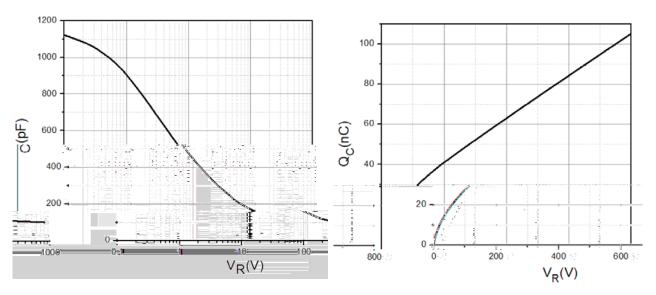


Figure 3. Capacitance vs. Reverse Voltage

Figure 4. Total Capacitance Charge vs. Reverse Voltage

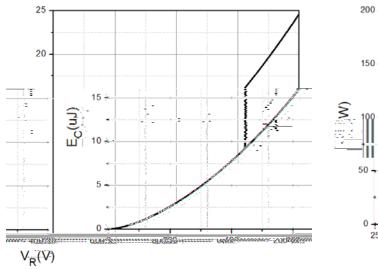


Figure 5. Capacitance Stored Energy

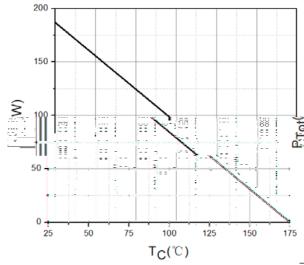


Figure 6. Power Derating

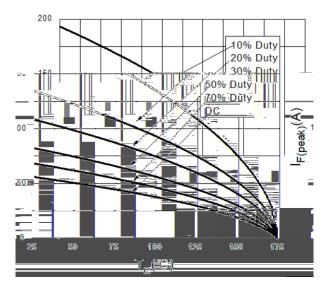


Figure 7. Current Derating

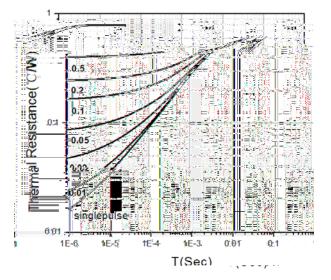


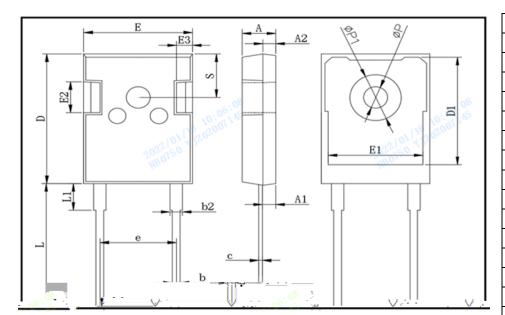
Figure 8. Transient Thermal Impedance







## **Outline Dimensions**



TO-247AC						
Dim	Min	Max				
Α	4.80	5.20				
A1	2.21	2.61				
A2	1.85	2.15				
b	1.11	1.36				
b2	1.91	2.21				
С	0.51	0.75				
D	20.70	21.30				
D1	16.25	16.85				
Е	15.50	16.10				
E1	13.00	13.60				
E2	4.80	5.20				
E3	2.30	2.70				
е	10.88BSC					
L	19.62	20.22				
L1	-	4.30				
Р	3.40	3.80				
P1	-	7.30				
S	6.15BSC					



# YJD106520NQG2



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